NSN 5961-01-123-2441

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-123-2441 **Inclosure Material:** Metal **Overall Length:** 0.082 inches **Terminal Length:** 0.064 inches **Overall Diameter:** 0.084 inches **End Application:** Radar **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1.0 reverse voltage, peak **Current Rating Per Characteristic:** 15.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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